

74HC4066-Q100; 74HCT4066-Q100

Quad single-pole single-throw analog switch

Rev. 3 — 16 December 2013

Product data sheet

1. General description

The 74HC4066-Q100; 74HCT4066-Q100 is a quad single pole, single throw analog switch. Each switch features two input/output terminals (nY and nZ) and an active HIGH enable input (nE). When nE is LOW, the analog switch is turned off. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} .

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - ◆ Specified from $-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$ and from $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$
- Input levels nE inputs:
 - ◆ For 74HC4066-Q100: CMOS level
 - ◆ For 74HCT4066-Q100: TTL level
- Low ON resistance:
 - ◆ $50\text{ }\Omega$ (typical) at $V_{CC} = 4.5\text{ V}$
 - ◆ $45\text{ }\Omega$ (typical) at $V_{CC} = 6.0\text{ V}$
 - ◆ $35\text{ }\Omega$ (typical) at $V_{CC} = 9.0\text{ V}$
- Specified in compliance with JEDEC standard no. 7A
- ESD protection:
 - ◆ MIL-STD-883, method 3015 exceeds 2000 V
 - ◆ HBM JESD22-A114F exceeds 2000 V
 - ◆ MM JESD22-A115-A exceeds 200 V ($C = 200\text{ pF}$, $R = 0\text{ }\Omega$)
- Multiple package options

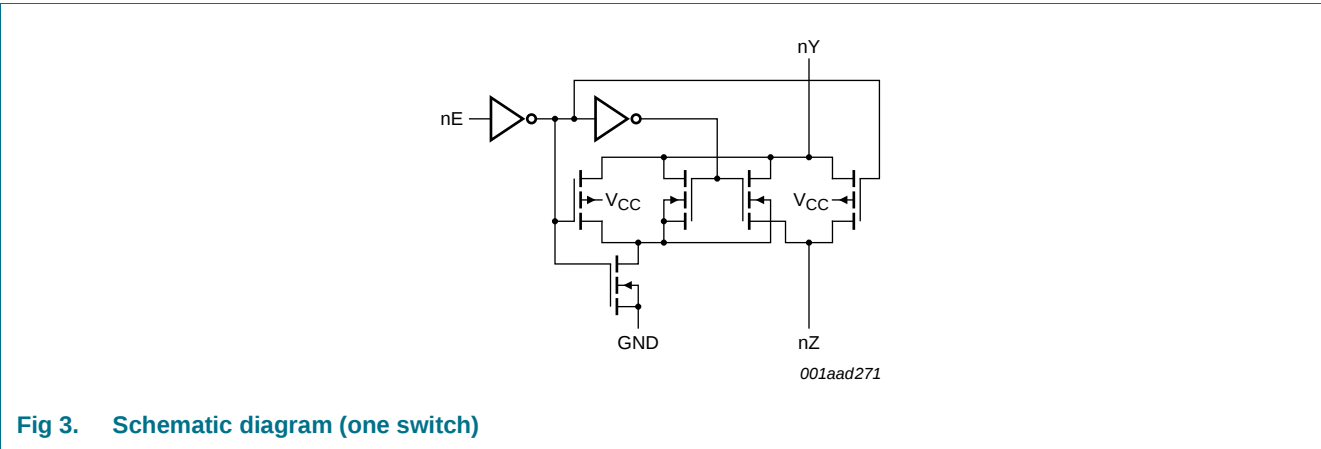
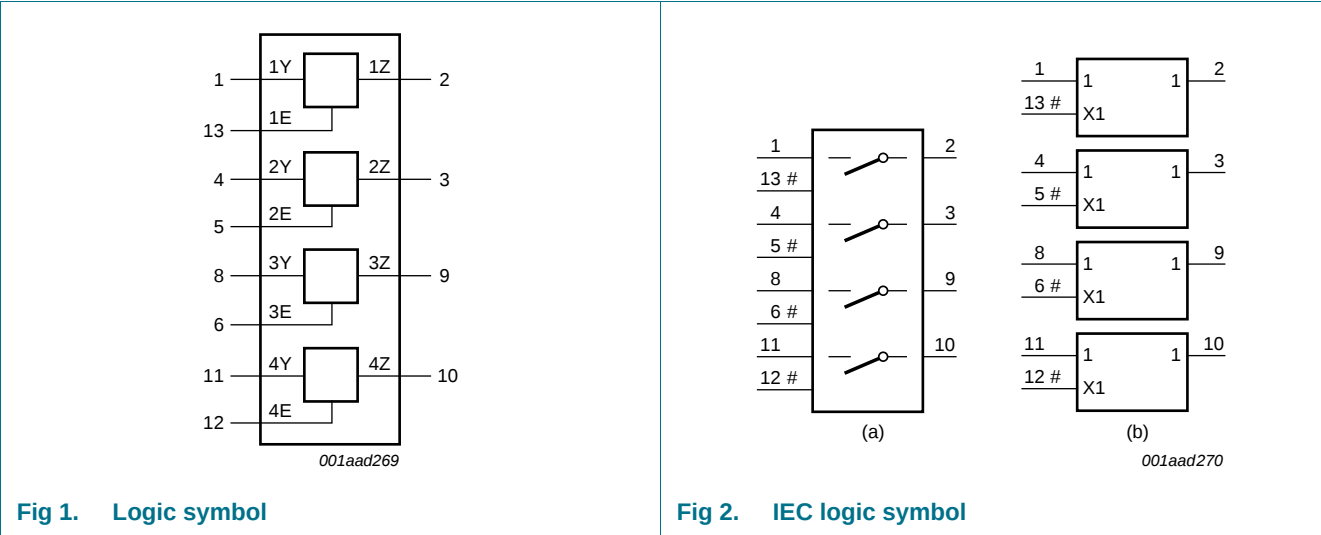


3. Ordering information

Table 1. Ordering information

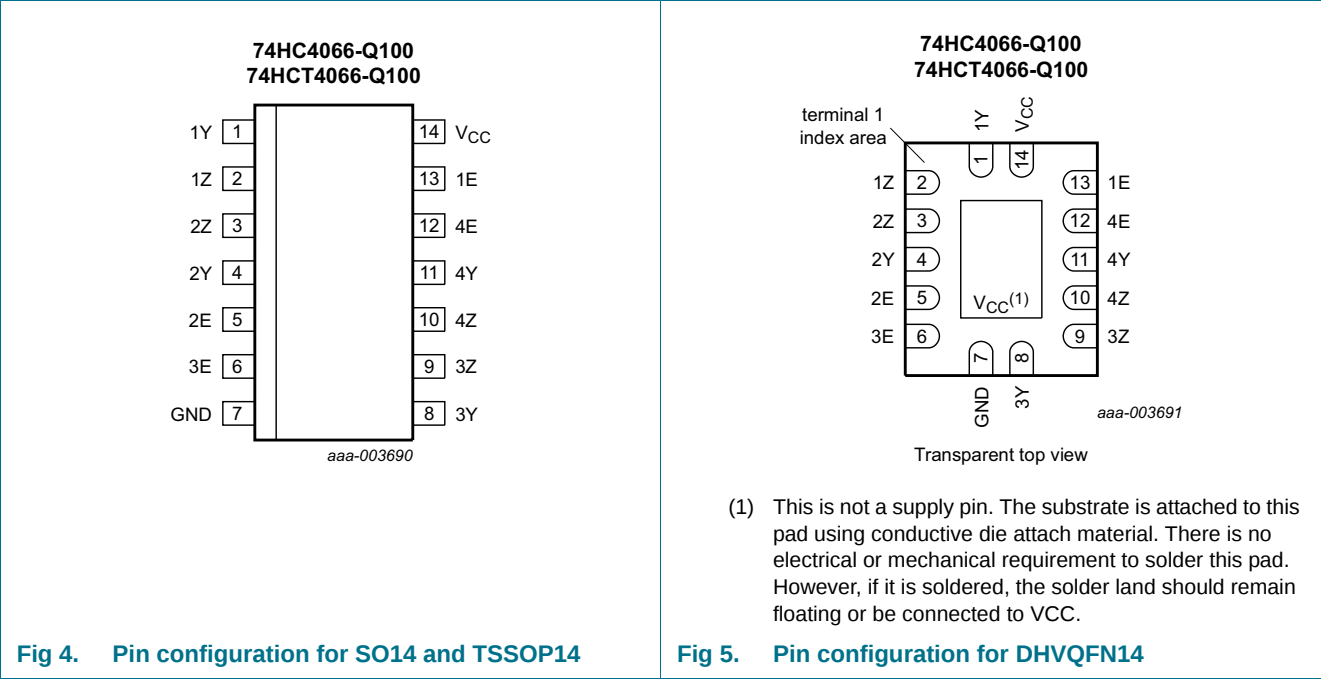
Type number	Package			
	Temperature range	Name	Description	Version
74HC4066D-Q100	−40 °C to +125 °C	SO14	plastic small outline package; 14 leads; body width 3.9 mm	SOT108-1
74HCT4066D-Q100				
74HC4066PW-Q100	−40 °C to +125 °C	TSSOP14	plastic thin shrink small outline package; 14 leads; body width 4.4 mm	SOT402-1
74HCT4066PW-Q100				
74HC4066BQ-Q100	−40 °C to +125 °C	DHVQFN14	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 × 3 × 0.85 mm	SOT762-1
74HCT4066BQ-Q100				

4. Functional diagram



5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
1Z, 2Z, 3Z, 4Z	2, 3, 9, 10	independent input or output
1Y, 2Y, 3Y, 4Y	1, 4, 8, 11	independent input or output
GND	7	ground (0 V)
1E, 2E, 3E, 4E	13, 5, 6, 12	enable input (active HIGH)
V _{CC}	14	supply voltage

6. Functional description

Table 3. Function table^[1]

Input nE	Switch
L	OFF
H	ON

- [1] H = HIGH voltage level;
L = LOW voltage level.

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+11.0	V
I_{IK}	input clamping current	$V_I < -0.5\text{ V}$ or $V_I > V_{CC} + 0.5\text{ V}$	-	±20	mA
I_{SK}	switch clamping current	$V_{SW} < -0.5\text{ V}$ or $V_{SW} > V_{CC} + 0.5\text{ V}$	-	±20	mA
I_{SW}	switch current	$V_{SW} = -0.5\text{ V}$ to $V_{CC} + 0.5\text{ V}$	^[1] -	±25	mA
I_{CC}	supply current		-	50	mA
I_{GND}	ground current		-	-50	mA
T_{stg}	storage temperature		-65	+150	°C
P_{tot}	total power dissipation	$T_{amb} = -40\text{ °C}$ to $+125\text{ °C}$	^[2]	-	500
P	power dissipation	per switch	-	100	mW

- [1] To avoid drawing V_{CC} current out of terminal Z, when switch current flows in terminals Yn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no V_{CC} current will flow out of terminals Yn. In this case there is no limit for the voltage drop across the switch, but the voltages at Yn and Z may not exceed V_{CC} or GND.
- [2] For SO14 packages: P_{tot} derates linearly with 8 mW/K above 70 °C.
For TSSOP14 packages: P_{tot} derates linearly with 5.5 mW/K above 60 °C.
For DHVQFN14 packages: P_{tot} derates linearly with 4.5 mW/K above 60 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	74HC4066-Q100			74HCT4066-Q100			Unit
			Min	Typ	Max	Min	Typ	Max	
V_{CC}	supply voltage		2.0	5.0	10.0	4.5	5.0	5.5	V
V_I	input voltage		GND	-	V_{CC}	GND	-	V_{CC}	V
V_{SW}	switch voltage		GND	-	V_{CC}	GND	-	V_{CC}	V
T_{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{CC} = 2.0\text{ V}$	-	-	625	-	-	-	ns/V
		$V_{CC} = 4.5\text{ V}$	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0\text{ V}$	-	-	83	-	-	-	ns/V
		$V_{CC} = 10.0\text{ V}$	-	-	35	-	-	-	ns/V

9. Static characteristics

Table 6. R_{ON} resistance per switch for types 74HC4066-Q100 and 74HCT4066-Q100

$V_I = V_{IH}$ or V_{IL} ; for test circuit see [Figure 6](#).

V_{IS} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

V_{OS} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

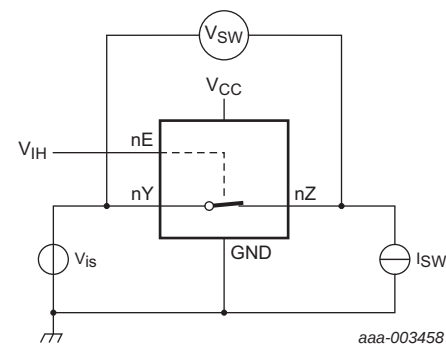
For 74HC4066-Q100: $V_{CC} - GND = 2.0\text{ V}$, 4.5 V , 6.0 V and 9.0 V .

For 74HCT4066-Q100: $V_{CC} - GND = 4.5\text{ V}$.

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ ^[1]	Max	Min	Max	
$R_{ON(peak)}$	ON resistance (peak)	$V_{IS} = V_{CC}$ to GND						
		$V_{CC} = 2.0\text{ V}$; $I_{SW} = 100\text{ }\mu\text{A}$ ^[2]	-	-	-	-	-	Ω
		$V_{CC} = 4.5\text{ V}$; $I_{SW} = 1000\text{ }\mu\text{A}$	-	54	-	118	142	Ω
		$V_{CC} = 6.0\text{ V}$; $I_{SW} = 1000\text{ }\mu\text{A}$	-	42	-	105	126	Ω
		$V_{CC} = 9.0\text{ V}$; $I_{SW} = 1000\text{ }\mu\text{A}$	-	32	-	88	105	Ω
$R_{ON(rail)}$	ON resistance (rail)	$V_{IS} = GND$						
		$V_{CC} = 2.0\text{ V}$; $I_{SW} = 100\text{ }\mu\text{A}$ ^[2]	-	80	-	-	-	Ω
		$V_{CC} = 4.5\text{ V}$; $I_{SW} = 1000\text{ }\mu\text{A}$	-	35	-	95	115	Ω
		$V_{CC} = 6.0\text{ V}$; $I_{SW} = 1000\text{ }\mu\text{A}$	-	27	-	82	100	Ω
		$V_{CC} = 9.0\text{ V}$; $I_{SW} = 1000\text{ }\mu\text{A}$	-	20	-	70	85	Ω
		$V_{IS} = V_{CC}$						
		$V_{CC} = 2.0\text{ V}$; $I_{SW} = 100\text{ }\mu\text{A}$ ^[2]	-	100	-	-	-	Ω
		$V_{CC} = 4.5\text{ V}$; $I_{SW} = 1000\text{ }\mu\text{A}$	-	42	-	106	128	Ω
		$V_{CC} = 6.0\text{ V}$; $I_{SW} = 1000\text{ }\mu\text{A}$	-	35	-	94	113	Ω
		$V_{CC} = 9.0\text{ V}$; $I_{SW} = 1000\text{ }\mu\text{A}$	-	20	-	78	95	Ω
ΔR_{ON}	ON resistance mismatch between channels	$V_{IS} = V_{CC}$ to GND						
		$V_{CC} = 2.0\text{ V}$ ^[2]	-	-	-	-	-	Ω
		$V_{CC} = 4.5\text{ V}$	-	5	-	-	-	Ω
		$V_{CC} = 6.0\text{ V}$	-	4	-	-	-	Ω
		$V_{CC} = 9.0\text{ V}$	-	3	-	-	-	Ω

[1] Typical values are measured at $T_{amb} = 25\text{ }^\circ\text{C}$.

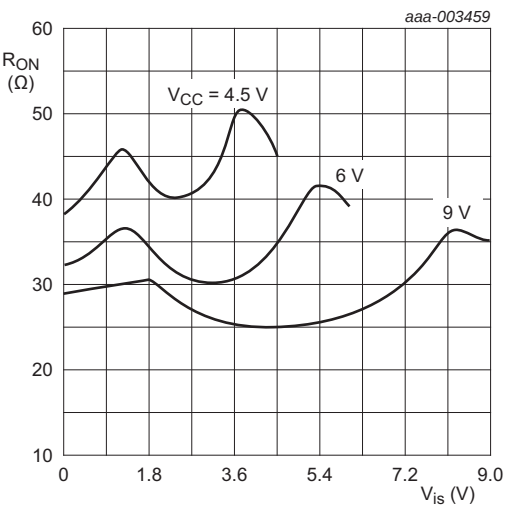
[2] At supply voltages ($V_{CC} - GND$) approaching 2 V, the analog switch ON resistance becomes extremely non-linear. Therefore it is recommended that these devices be used to transmit digital signals only, when using these supply voltages.



$V_{IS} = 0\text{ V to }V_{CC}$

$$R_{ON} = \frac{V_{SW}}{I_{SW}}$$

Fig 6. Test circuit for measuring R_{ON}



$V_{IS} = 0\text{ V to }V_{CC}$

Fig 7. Typical R_{ON} as a function of input voltage V_{IS}

Table 7. Static characteristics 74HC4066-Q100

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

V_{IS} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

V_{OS} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ ^[1]	Max	Unit
$T_{amb} = -40\text{ °C to }+85\text{ °C}$						
V_{IH}	HIGH-level input voltage	$V_{CC} = 2.0\text{ V}$	1.5	1.2	-	V
		$V_{CC} = 4.5\text{ V}$	3.15	2.4	-	V
		$V_{CC} = 6.0\text{ V}$	4.2	3.2	-	V
		$V_{CC} = 9.0\text{ V}$	6.3	4.7	-	V
V_{IL}	LOW-level input voltage	$V_{CC} = 2.0\text{ V}$	-	0.8	0.5	V
		$V_{CC} = 4.5\text{ V}$	-	2.1	1.35	V
		$V_{CC} = 6.0\text{ V}$	-	2.8	1.80	V
		$V_{CC} = 9.0\text{ V}$	-	4.3	2.70	V
I_I	input leakage current	$V_I = V_{CC}\text{ or GND}$				
		$V_{CC} = 6.0\text{ V}$	-	-	± 1.0	μA
		$V_{CC} = 10.0\text{ V}$	-	-	± 2.0	μA
$I_{S(OFF)}$	OFF-state leakage current	$V_{CC} = 10.0\text{ V}; V_I = V_{IH}\text{ or }V_{IL};$ $ V_{SW} = V_{CC} - \text{GND};$ see Figure 8				
		per channel	-	-	± 1.0	μA
$I_{S(ON)}$	ON-state leakage current	$V_{CC} = 10.0\text{ V}; V_I = V_{IH}\text{ or }V_{IL};$ $ V_{SW} = V_{CC} - \text{GND};$ see Figure 9				
			-	-	± 1.0	μA

Table 7. Static characteristics 74HC4066-Q100 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

V_{IS} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

V_{OS} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ ^[1]	Max	Unit
I_{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{IS} =$ GND or V_{CC} ; $V_{OS} = V_{CC}$ or GND				
		$V_{CC} = 6.0$ V	-	-	20.0	μ A
		$V_{CC} = 10.0$ V	-	-	40.0	μ A
C_I	input capacitance		-	3.5	-	pF
C_{SW}	switch capacitance		-	8	-	pF
$T_{amb} = -40$ °C to $+125$ °C						
V_{IH}	HIGH-level input voltage	$V_{CC} = 2.0$ V	1.5	-	-	V
		$V_{CC} = 4.5$ V	3.15	-	-	V
		$V_{CC} = 6.0$ V	4.2	-	-	V
		$V_{CC} = 9.0$ V	6.3	-	-	V
V_{IL}	LOW-level input voltage	$V_{CC} = 2.0$ V	-	-	0.50	V
		$V_{CC} = 4.5$ V	-	-	1.35	V
		$V_{CC} = 6.0$ V	-	-	1.80	V
		$V_{CC} = 9.0$ V	-	-	2.70	V
I_I	input leakage current	$V_I = V_{CC}$ or GND				
		$V_{CC} = 6.0$ V	-	-	± 1.0	μ A
		$V_{CC} = 10.0$ V	-	-	± 2.0	μ A
$I_{S(OFF)}$	OFF-state leakage current	$V_{CC} = 10.0$ V; $V_I = V_{IH}$ or V_{IL} ; $ V_{SW} = V_{CC} - \text{GND}$; see Figure 8				
		per channel	-	-	± 1.0	μ A
$I_{S(ON)}$	ON-state leakage current	$V_{CC} = 10.0$ V; $V_I = V_{IH}$ or V_{IL} ; $ V_{SW} = V_{CC} - \text{GND}$; see Figure 9	-	-	± 1.0	μ A
I_{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{IS} =$ GND or V_{CC} ; $V_{OS} = V_{CC}$ or GND				
		$V_{CC} = 6.0$ V	-	-	40	μ A
		$V_{CC} = 10.0$ V	-	-	80	μ A

[1] Typical values are measured at $T_{amb} = 25$ °C.

Table 8. Static characteristics 74HCT4066-Q100

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

V_{IS} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

V_{OS} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ ^[1]	Max	Unit
$T_{amb} = -40$ °C to $+85$ °C						
V_{IH}	HIGH-level input voltage	$V_{CC} = 4.5$ V to 5.5 V	2.0	1.6	-	V
V_{IL}	LOW-level input voltage	$V_{CC} = 4.5$ V to 5.5 V	-	1.2	0.8	V
I_I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5$ V	-	-	± 1.0	μ A

Table 8. Static characteristics 74HCT4066-Q100 ...continued

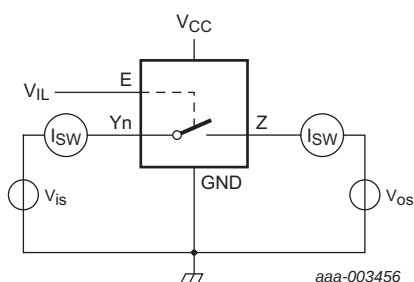
At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

V_{IS} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

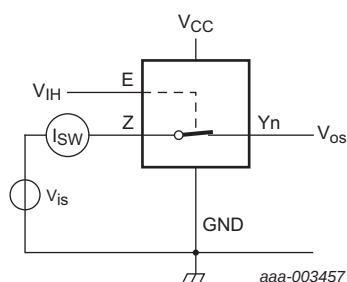
V_{OS} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ ^[1]	Max	Unit
$I_{S(OFF)}$	OFF-state leakage current	$V_{CC} = 5.5\text{ V}$; $V_I = V_{IH}$ or V_{IL} ; $ V_{SW} = V_{CC} - \text{GND}$; see Figure 8 per channel	-	-	± 1.0	μA
$I_{S(ON)}$	ON-state leakage current	$V_{CC} = 5.5\text{ V}$; $V_I = V_{IH}$ or V_{IL} ; $ V_{SW} = V_{CC} - \text{GND}$; see Figure 9	-	-	± 1.0	μA
I_{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{IS} = \text{GND}$ or V_{CC} ; $V_{OS} = V_{CC}$ or GND; $V_{CC} = 4.5\text{ V}$ to 5.5 V	-	-	20.0	μA
ΔI_{CC}	additional supply current	per input pin; $V_I = V_{CC} - 2.1\text{ V}$; other inputs at V_{CC} or GND; $V_{CC} = 4.5\text{ V}$ to 5.5 V	-	100	450	μA
C_I	input capacitance		-	3.5	-	pF
C_{SW}	switch capacitance		-	8	-	pF
$T_{amb} = -40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$						
V_{IH}	HIGH-level input voltage	$V_{CC} = 4.5\text{ V}$ to 5.5 V	2.0	-	-	V
V_{IL}	LOW-level input voltage	$V_{CC} = 4.5\text{ V}$ to 5.5 V	-	-	0.8	V
I_I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5\text{ V}$	-	-	± 1.0	μA
$I_{S(OFF)}$	OFF-state leakage current	$V_{CC} = 5.5\text{ V}$; $V_I = V_{IH}$ or V_{IL} ; $ V_{SW} = V_{CC} - \text{GND}$; see Figure 8 per channel	-	-	± 1.0	μA
$I_{S(ON)}$	ON-state leakage current	$V_{CC} = 5.5\text{ V}$; $V_I = V_{IH}$ or V_{IL} ; $ V_{SW} = V_{CC} - \text{GND}$; see Figure 9	-	-	± 1.0	μA
I_{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{IS} = \text{GND}$ or V_{CC} ; $V_{OS} = V_{CC}$ or GND; $V_{CC} = 4.5\text{ V}$ to 5.5 V	-	-	40	μA
ΔI_{CC}	additional supply current	per input pin; $V_I = V_{CC} - 2.1\text{ V}$; other inputs at V_{CC} or GND; $V_{CC} = 4.5\text{ V}$ to 5.5 V	-	-	490	μA

[1] Typical values are measured at $T_{amb} = 25\text{ }^{\circ}\text{C}$.



$V_{IS} = V_{CC}$ and $V_{OS} = \text{GND}$
 $V_{IS} = \text{GND}$ and $V_{OS} = V_{CC}$

Fig. 8. Test circuit for measuring OFF-state leakage current

$V_{IS} = V_{CC}$ and $V_{OS} = \text{open}$
 $V_{IS} = \text{GND}$ and $V_{OS} = \text{open}$

Fig. 9. Test circuit for measuring ON-state leakage current

10. Dynamic characteristics

Table 9. Dynamic characteristics 74HC4066-Q100

$GND = 0\text{ V}$; $t_r = t_f = 6\text{ ns}$; $C_L = 50\text{ pF}$ unless specified otherwise; for test circuit see [Figure 12](#).

V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

V_{os} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	–40 °C to +85 °C			–40 °C to +125 °C		Unit
			Min	Typ ^[1]	Max	Min	Max	
t_{pd}	propagation delay	nY to nZ or nZ to nY; $R_L = \infty\ \Omega$; see Figure 10 ^[2]						
		$V_{CC} = 2.0\text{ V}$	-	8	75	-	90	ns
		$V_{CC} = 4.5\text{ V}$	-	3	15	-	18	ns
		$V_{CC} = 6.0\text{ V}$	-	2	13	-	15	ns
		$V_{CC} = 9.0\text{ V}$	-	2	10	-	12	ns
t_{off}	turn-off time	nE to nY or nZ; see Figure 11 ^[4]						
		$V_{CC} = 2.0\text{ V}$	-	44	190	-	225	ns
		$V_{CC} = 4.5\text{ V}$	-	16	38	-	45	ns
		$V_{CC} = 5.0\text{ V}$; $C_L = 15\text{ pF}$	-	13	-	-	-	ns
		$V_{CC} = 6.0\text{ V}$	-	13	33	-	38	ns
		$V_{CC} = 9.0\text{ V}$	-	16	26	-	30	ns
t_{on}	turn-on time	nE to nY or nZ; see Figure 11 ^[3]						
		$V_{CC} = 2.0\text{ V}$	-	36	125	-	150	ns
		$V_{CC} = 4.5\text{ V}$	-	13	25	-	30	ns
		$V_{CC} = 5.0\text{ V}$; $C_L = 15\text{ pF}$	-	11	-	-	-	ns
		$V_{CC} = 6.0\text{ V}$	-	10	21	-	26	ns
		$V_{CC} = 9.0\text{ V}$	-	8	16	-	20	ns
C_{PD}	power dissipation capacitance	per switch; $V_i = GND$ to V_{CC} ^[5]	11		-	-	-	pF

[1] Typical values are measured at $T_{amb} = 25\text{ °C}$.

[2] t_{pd} is the same as t_{PHL} and t_{PLH} .

[3] t_{on} is the same as t_{PHZ} and t_{PLZ} .

[4] t_{off} is the same as t_{PZH} and t_{PZL} .

[5] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum\{(C_L + C_{SW}) \times V_{CC}^2 \times f_o\}$ where:

f_i = input frequency in MHz;

f_o = output frequency in MHz;

$\sum\{(C_L + C_{SW}) \times V_{CC}^2 \times f_o\}$ = sum of outputs;

C_L = output load capacitance in pF;

C_{SW} = switch capacitance in pF;

V_{CC} = supply voltage in V.

Table 10. Dynamic characteristics 74HCT4066-Q100

$GND = 0\text{ V}$; $t_r = t_f = 6\text{ ns}$; $C_L = 50\text{ pF}$ unless specified otherwise; for test circuit see [Figure 12](#).

V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

V_{os} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	–40 °C to +85 °C			–40 °C to +125 °C		Unit
			Min	Typ ^[1]	Max	Min	Max	
t_{pd}	propagation delay	nY to nZ or nZ to nY; $R_L = \infty\ \Omega$; see Figure 10 ^[2]						
		$V_{CC} = 4.5\text{ V}$	-	3	15	-	18	ns
t_{off}	turn-off time	nE to nY or nZ; see Figure 11 ^[4]						
		$V_{CC} = 4.5\text{ V}$	-	20	44	-	53	ns
		$V_{CC} = 5.0\text{ V}$; $C_L = 15\text{ pF}$	-	16	-	-	-	ns
t_{on}	turn-on time	nE to nY or nZ; see Figure 11 ^[3]						
		$V_{CC} = 4.5\text{ V}$	-	12	30	-	36	ns
		$V_{CC} = 5.0\text{ V}$; $C_L = 15\text{ pF}$	-	12	-	-	-	ns
C_{PD}	power dissipation capacitance	per switch; $V_I = GND$ to $(V_{CC} - 1.5\text{ V})$ ^[5]	-	12	-	-	-	pF

[1] Typical values are measured at $T_{amb} = 25\text{ °C}$.

[2] t_{pd} is the same as t_{PHL} and t_{PLH} .

[3] t_{on} is the same as t_{PHZ} and t_{PLZ} .

[4] t_{off} is the same as t_{PZH} and t_{PZL} .

[5] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum\{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\}$ where:

f_i = input frequency in MHz;

f_o = output frequency in MHz;

$\sum\{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\}$ = sum of outputs;

C_L = output load capacitance in pF;

C_{sw} = switch capacitance in pF;

V_{CC} = supply voltage in V.

11. Waveforms

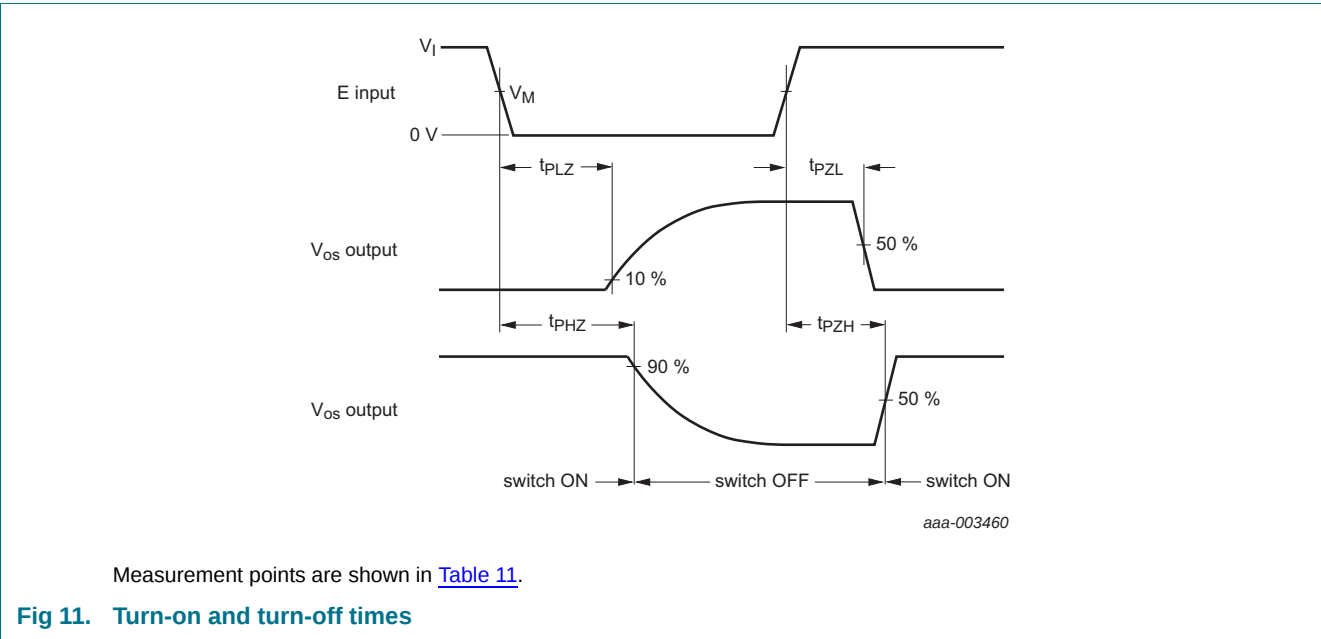
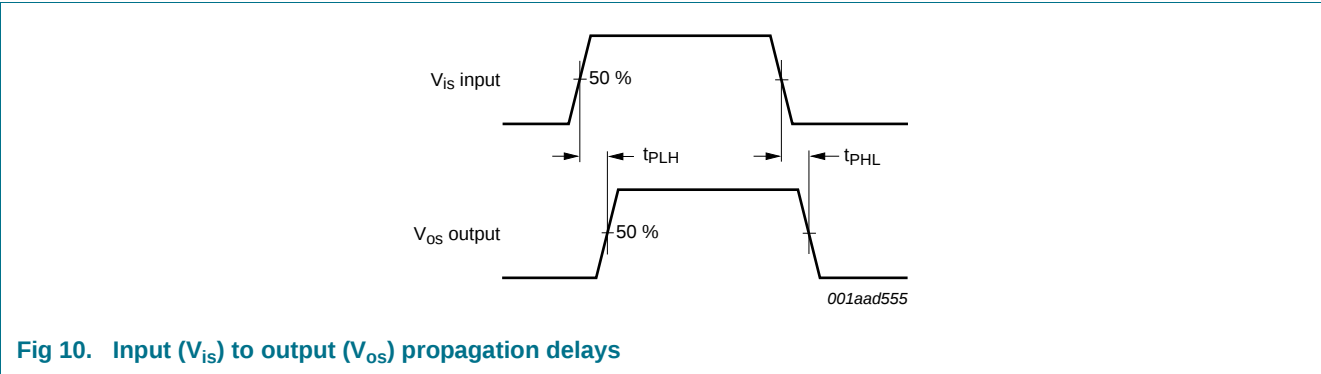


Table 11. Measurement points

Type	V_I	V_M
74HC4066-Q100	V_{CC}	$0.5V_{CC}$
74HCT4066-Q100	3.0 V	1.3 V

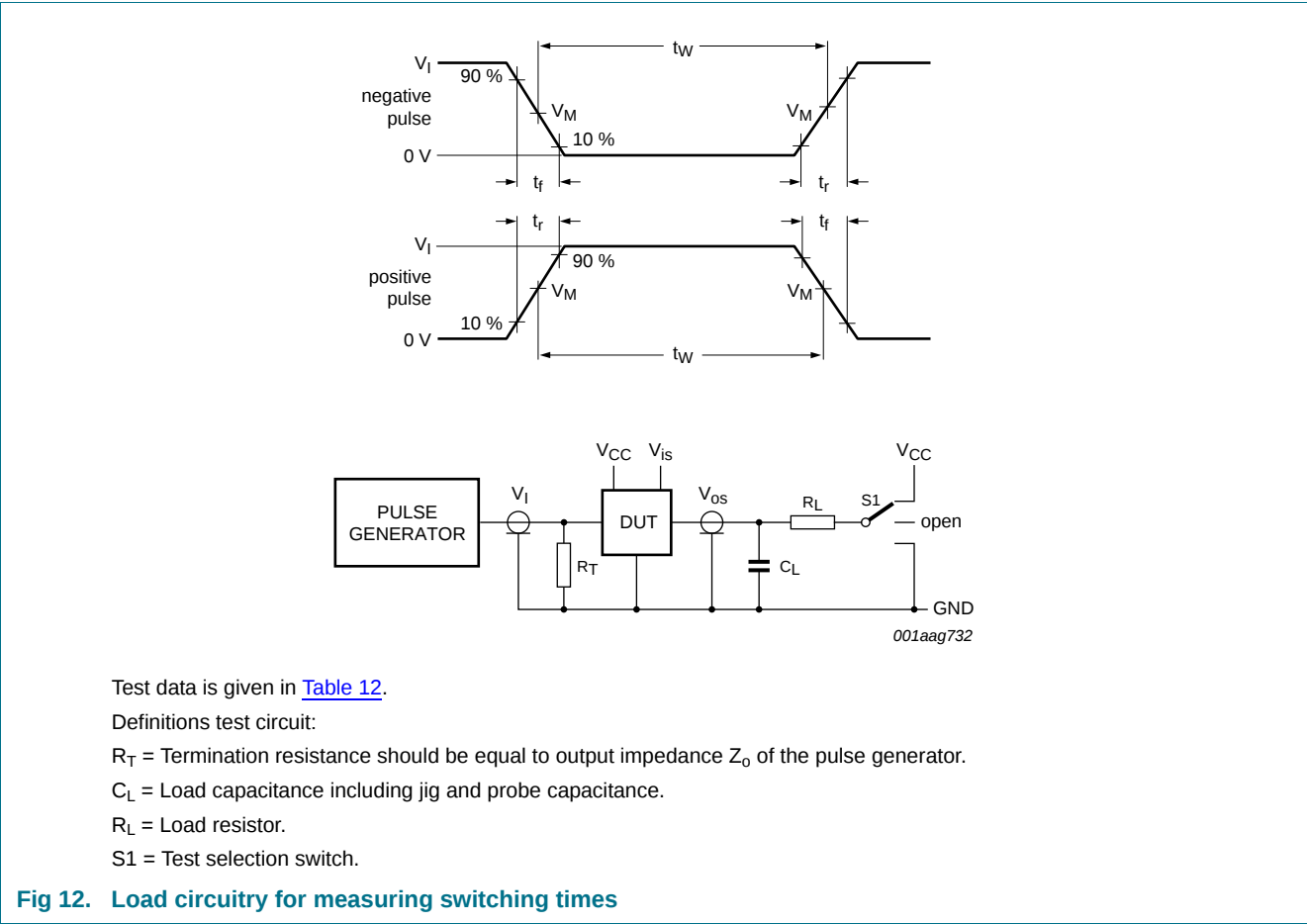


Table 12. Test data

Test	Input			Output		S1 position
	Control E	Switch Yn (Z)	t _r , t _f	Switch Z (Yn)		
	V _I [1]	V _{is}		C _L	R _L	
t _{PHL} , t _{PLH}	GND	GND to V _{CC}	6 ns	50 pF	-	open
t _{PHZ} , t _{PZH}	GND to V _{CC}	V _{CC}	6 ns	50 pF, 15 pF	1 kΩ	GND
t _{PLZ} , t _{PZL}	GND to V _{CC}	GND	6 ns	50 pF, 15 pF	1 kΩ	V _{CC}

[1] For 74HCT4066-Q100: maximum input voltage $V_I = 3.0$ V.

12. Additional dynamic characteristics

Table 13. Additional dynamic characteristics

Recommended conditions and typical values; $GND = 0\text{ V}$; $T_{amb} = 25\text{ }^{\circ}\text{C}$.

V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

V_{os} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

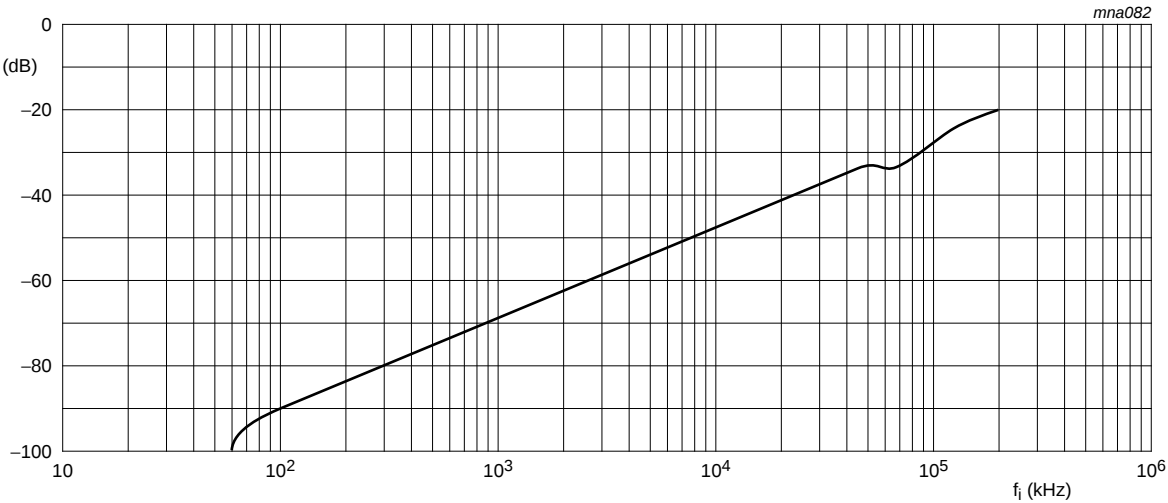
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
THD	total harmonic distortion	$f_i = 1\text{ kHz}$; $R_L = 10\text{ k}\Omega$; $C_L = 50\text{ pF}$; see Figure 13				%
		$V_{CC} = 4.5\text{ V}$; $V_i = 4.0\text{ V (p-p)}$	-	0.04	-	%
		$V_{CC} = 9.0\text{ V}$; $V_i = 8.0\text{ V (p-p)}$	-	0.02	-	%
		$f_i = 10\text{ kHz}$; $R_L = 10\text{ k}\Omega$; $C_L = 50\text{ pF}$; see Figure 13				
		$V_{CC} = 4.5\text{ V}$; $V_i = 4.0\text{ V (p-p)}$	-	0.12	-	%
		$V_{CC} = 9.0\text{ V}$; $V_i = 8.0\text{ V (p-p)}$	-	0.06	-	%
$f_{(-3dB)}$	-3 dB frequency response	$R_L = 50\text{ }\Omega$; $C_L = 10\text{ pF}$; see Figure 15	[2]			
		$V_{CC} = 4.5\text{ V}$	-	180	-	MHz
		$V_{CC} = 9.0\text{ V}$	-	200	-	MHz
α_{iso}	isolation (OFF-state)	$R_L = 600\text{ }\Omega$; $C_L = 50\text{ pF}$; $f_i = 1\text{ MHz}$; see Figure 14	[1]			
		$V_{CC} = 4.5\text{ V}$	-	-50	-	dB
		$V_{CC} = 9.0\text{ V}$	-	-50	-	dB
V_{ct}	crosstalk voltage	between digital input and switch (peak to peak value); $R_L = 600\text{ }\Omega$; $C_L = 50\text{ pF}$; $f_i = 1\text{ MHz}$; see Figure 16				
		$V_{CC} = 4.5\text{ V}$	-	110	-	mV
		$V_{CC} = 9.0\text{ V}$	-	220	-	mV
Xtalk	crosstalk	between switches; $R_L = 600\text{ }\Omega$; $C_L = 50\text{ pF}$; $f_i = 1\text{ MHz}$; see Figure 17	[1]			
		$V_{CC} = 4.5\text{ V}$	-	-60	-	dB
		$V_{CC} = 9.0\text{ V}$	-	-60	-	dB

[1] Adjust input voltage V_{is} to 0 dBm level (0 dBm = 1 mW into 600 Ω).

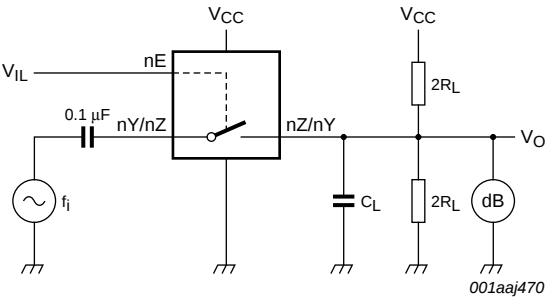
[2] Adjust input voltage V_{is} to 0 dBm level at V_{os} for $f_i = 1\text{ MHz}$ (0 dBm = 1 mW into 50 Ω). After set-up, f_i is increased to obtain a reading of -3 dB at V_{os} .



Fig 13. Test circuit for measuring total harmonic distortion



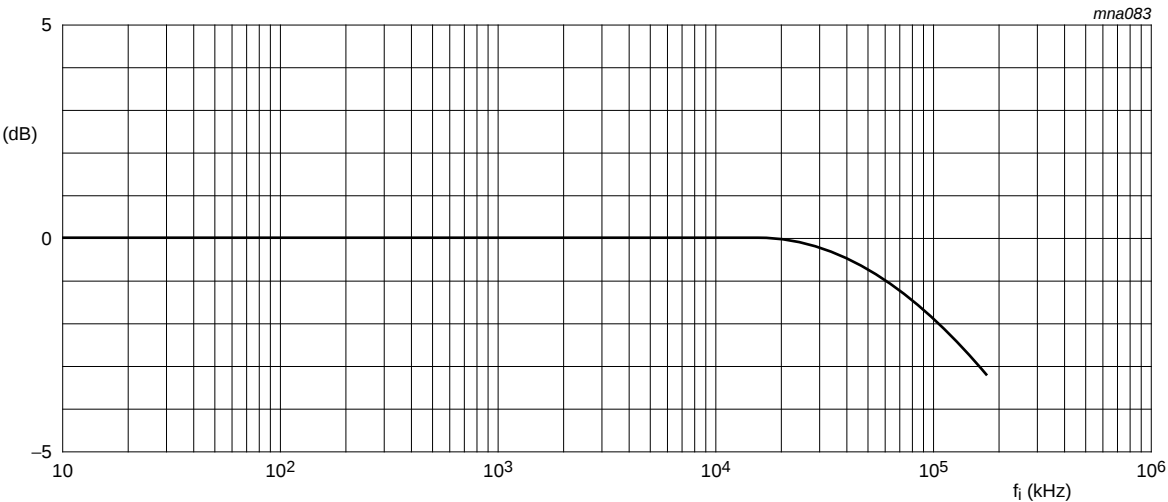
a. Isolation (OFF-state)



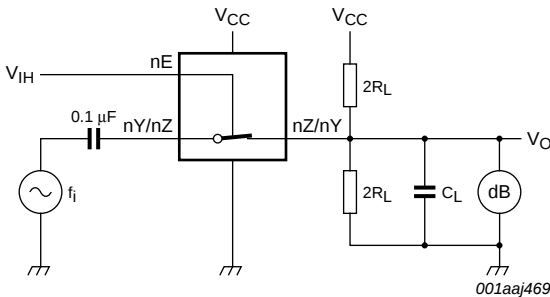
b. Test circuit

$V_{CC} = 4.5\text{ V}$; $GND = 0\text{ V}$; $R_L = 600\text{ }\Omega$; $R_{source} = 1\text{ k}\Omega$.

Fig 14. Isolation (OFF-state) as a function of frequency



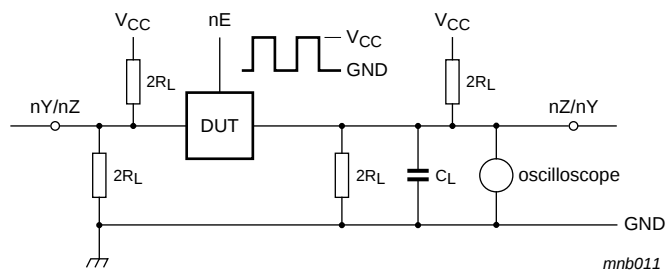
a. Typical -3 dB frequency response



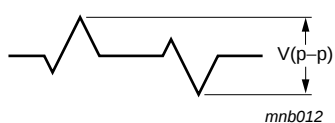
b. Test circuit

$V_{CC} = 4.5\text{ V}$; $\text{GND} = 0\text{ V}$; $R_L = 50\ \Omega$; $R_{\text{source}} = 1\ \text{k}\Omega$.

Fig 15. -3 dB frequency response



a. Circuit



b. Crosstalk voltage

Fig 16. Test circuit for measuring crosstalk voltage (between the digital input and the switch)

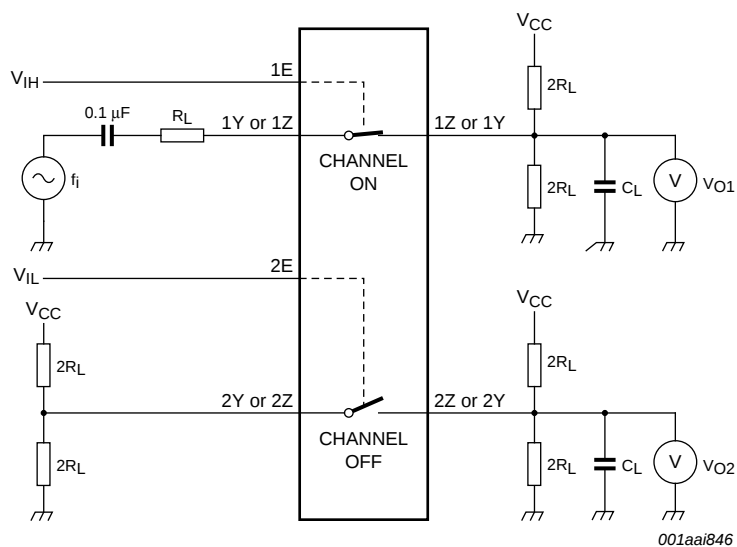


Fig 17. Test circuit for measuring crosstalk (between the switches)

13. Package outline

SO14: plastic small outline package; 14 leads; body width 3.9 mm SOT108-1

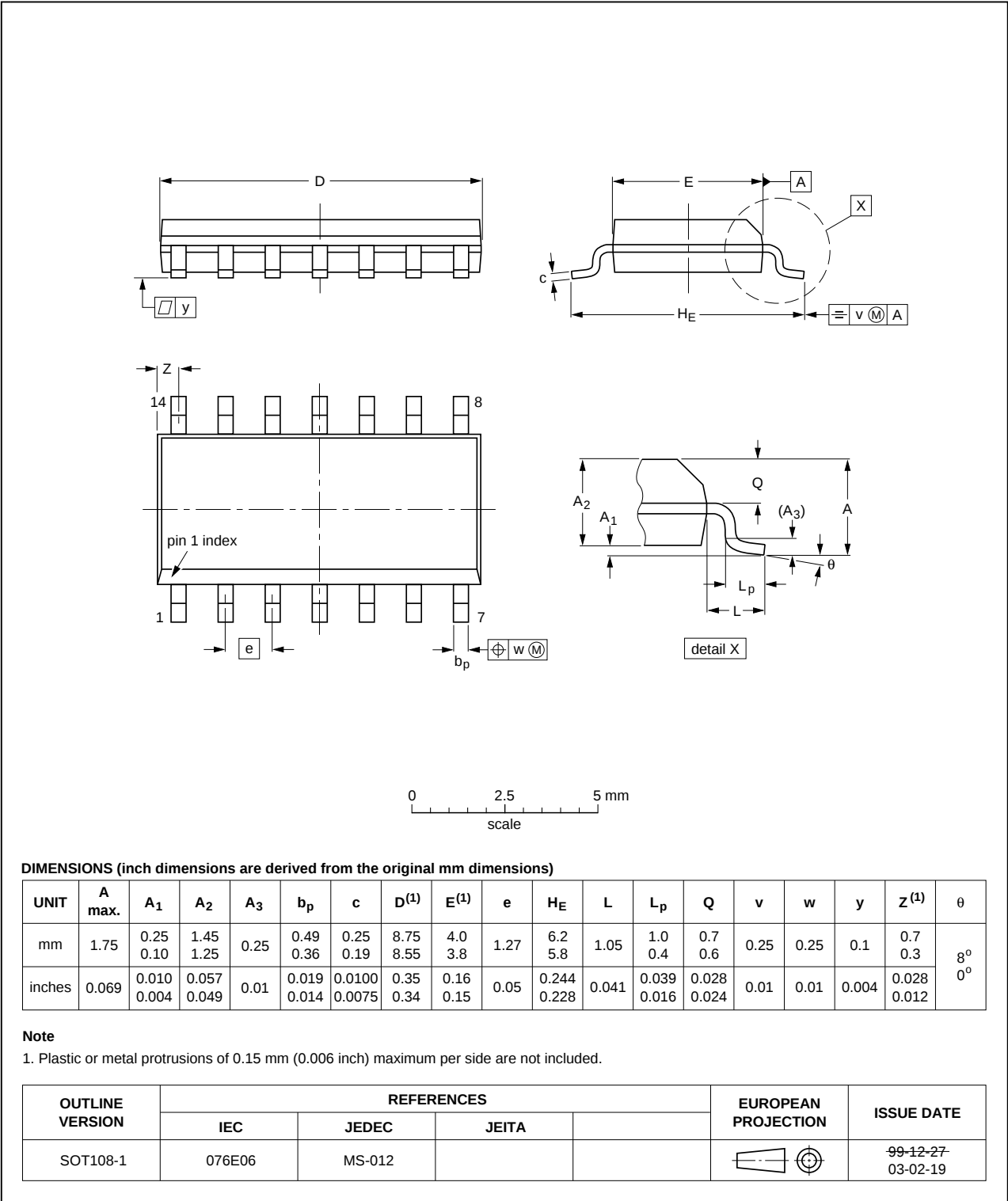
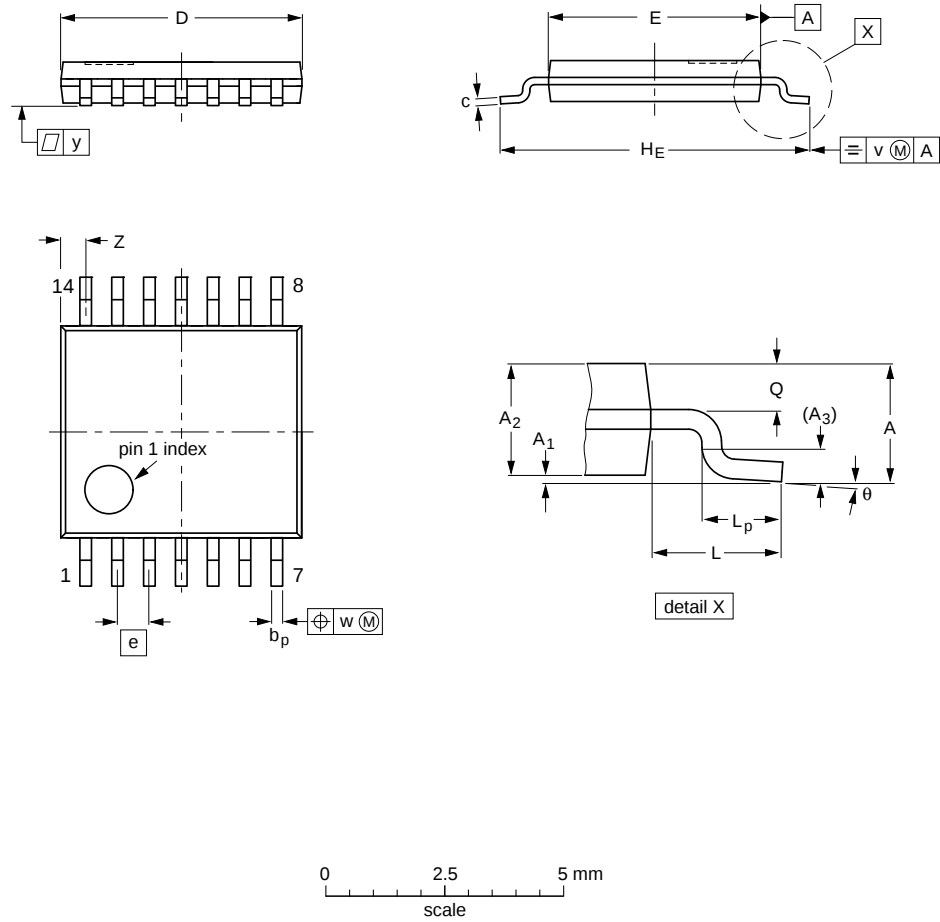


Fig 18. Package outline SOT108-1 (SO14)

TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽²⁾	e	H _E	L	L _p	Q	v	w	y	Z ⁽¹⁾	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.72 0.38	8° 0°

- Notes**
1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT402-1		MO-153				99-12-27 03-02-18

Fig 19. Package outline SOT402-1 (TSSOP14)

DHVQFN14: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 x 3 x 0.85 mm

SOT762-1

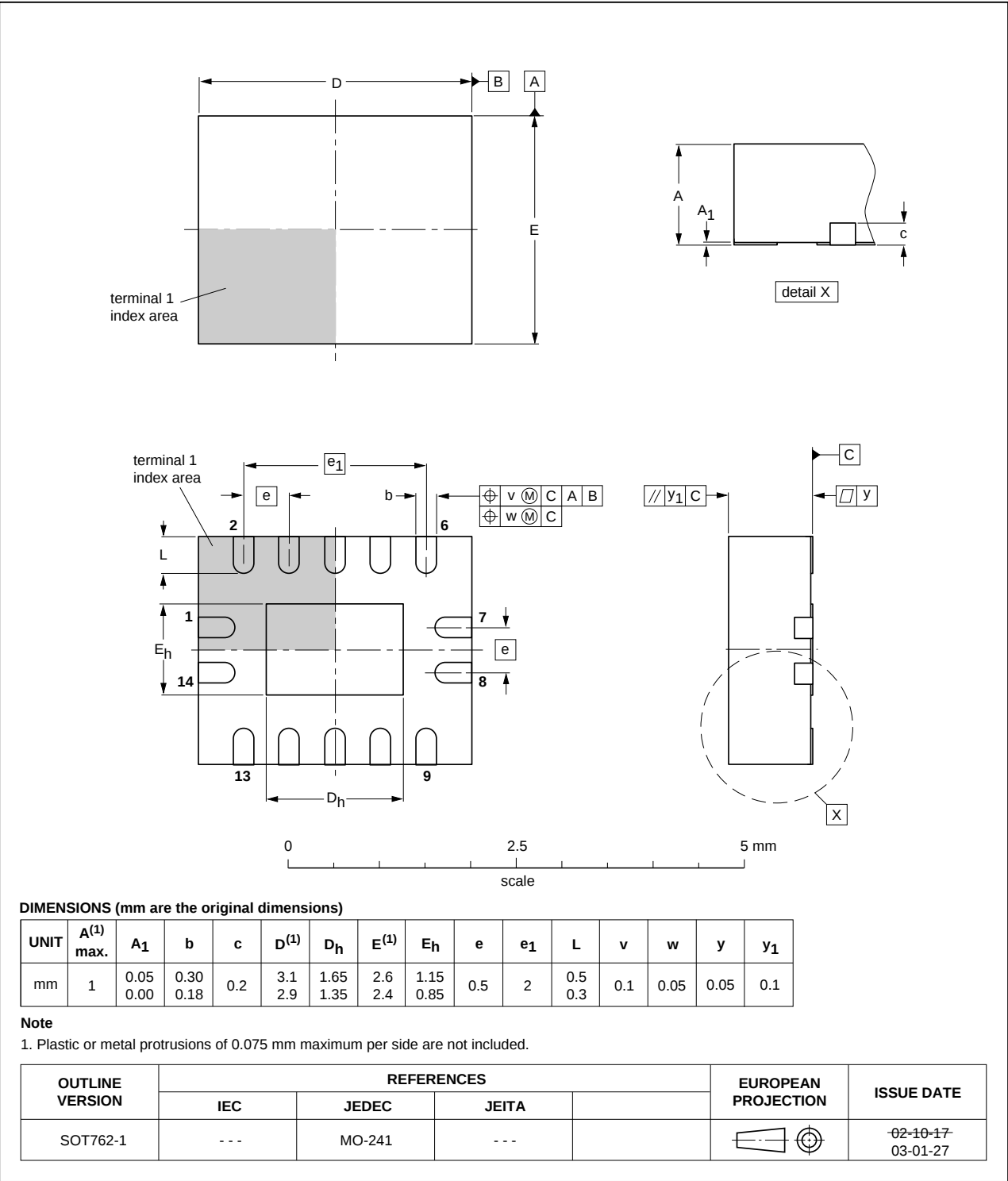


Fig 20. Package outline SOT762-1 (DHVQFN14)

14. Abbreviations

Table 14. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
CDM	Charge-Device Model
MIL	Military

15. Revision history

Table 15. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT4066_Q100 v.3	20131216	Product data sheet	-	74HC_HCT4066_Q100 v.2
Modifications:	• Features and benefits updated (errata).			
74HC_HCT4066_Q100 v.2	20130404	Product data sheet	-	74HC_HCT4066_Q100 v.1
Modifications:	• Descriptive title corrected (errata).			
	• New general description (errata).			
74HC_HCT4066_Q100 v.1	20120712	Product data sheet	-	-

16. Legal information

16.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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18. Contents

1	General description	1
2	Features and benefits	1
3	Ordering information	2
4	Functional diagram	2
5	Pinning information	3
5.1	Pinning	3
5.2	Pin description	3
6	Functional description	4
7	Limiting values	4
8	Recommended operating conditions	4
9	Static characteristics	5
10	Dynamic characteristics	9
11	Waveforms	11
12	Additional dynamic characteristics	13
13	Package outline	17
14	Abbreviations	20
15	Revision history	20
16	Legal information	21
16.1	Data sheet status	21
16.2	Definitions	21
16.3	Disclaimers	21
16.4	Trademarks	22
17	Contact information	22
18	Contents	23

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